

TDA7365

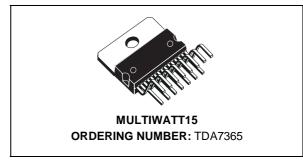
2 x 6W CAR RADIO AMPLIFIER PLUS SOLID STATE SWITCH

ADVANCE DATA

- OUTPUT POWER 2x6W/4 Ω @14.4V, 1KHz, 10%
- SOLID STATE POWER SWITCH INCLUDED (1A @ V_{DROP} = 0.8V Typ.)
- MINIMUM EXTERNAL COMPONENT COUNT
 - INTERNALLY FIXED GAIN (40dB)
 - NO BOOTSTRAP CAPACITORS
 - NO EXTERNAL COMPENSATION
- ST-BY FUNCTION (CMOS COMPATIBLE)
- MUTE FUNCTION (CMOS COMPATIBLE)
- NO AUDIBLE POP DURING MUTE/ST-BY OPERATIONS
- LOW SUPPLY SELF MUTING

PROTECTIONS

- AC AUDIO OUTPUTS SHORT CIRCUIT TO GND
- DC AUDIO OUTPUTS SHORT CIRCUIT TO GND AND TO V_S AT POWER ON
- SWITCH OUTPUT INTERNAL CURRENT LIMITATION
- OVERRATING CHIP TEMPERATURE WITH SOFT THERMAL LIMITER
- LOAD DUMP
- FORTUITOUS OPEN GND



- REVERSE BATTERY
- ESD

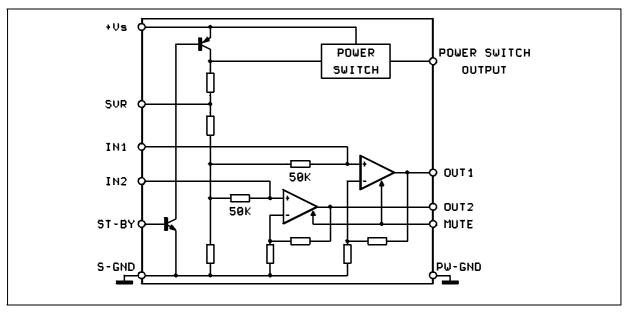
DESCRIPTION

The TDA7365 is a new technology Dual Audio Amplifier in Multiwatt15 package especially designed for stereo car radio applications.

Thanks to the fully complementary output configuration the TDA7365 delivers a rail to rail voltage swing with no need of boostrap capacitors

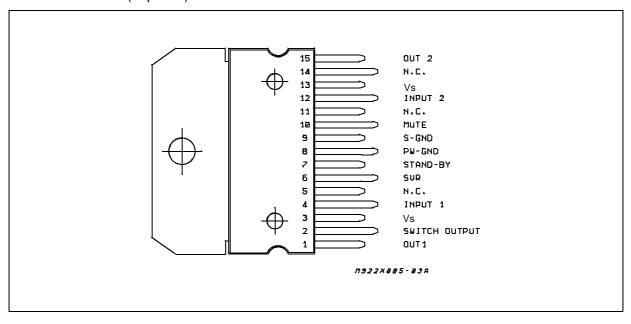
It includes a solid state switch, enabled by a ST-BY function common to the audio section, suitable for supplying both the signal processing part of the car radio set and the lamps. As a results the power-on operation is simplified, thereby saving cost and space in the whole power section.

BLOCK DIAGRAM



April 1995 1/7

PIN CONNECTION (Top view)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
Vs	DC Supply Voltage	28	V	
V_{OP}	Operating Supply Voltage	18	V	
V_{PEAK}	Peak Supply Voltage (t = 50ms)	40	V	
lo	Audio Channels Output Peak Current (not rep. t = 100μs)	4	Α	
lo	Audio Channels Output Peak Current (rep. f > 10Hz)	3	Α	
lo	Switch Output Peak Current	(internally limited) 1.5	Α	
P _{tot}	Power Dissipation (T _{case} = 85°C)	32	W	
T _{stg} , T _j	Storage and Junction Temperature	-40 to 150	°C	

THERMAL DATA

Symbol	Description		Value	Unit
R _{th j-case}	Thermal Resistance Junction-case	Max	2	°C/W

ELECTRICAL CHARACTERISTICS (Refer to the test circuit; $V_S = 14.4V$; $R_L = 4\Omega$, $T_{amb} = 25^{\circ}C$, f = 1kHz, unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Range		8		18	V
l _d	Total Quiescent Drain Current	Power Switch Unloaded		80		mA
Po	Output Power	$R_L = 4\Omega$; THD = 10% each channel	5.5	6		W
		$R_L = 2\Omega$; THD = 10% each channel		9		W
d	Distortion	$P_0 = 0.1 \text{ to } 3W$		0.08	0.3	%
СТ	Cross Talk	$f = 1kHz; R_g = 0$ $f = 10kHz; R_g = 0$	50	55 50		dB dB
R _{IN}	Input Impedance		40	50		ΚΩ
G_V	Voltage Gain		39	40	41	dB
G_V	Voltage Gain Match.				1	dB
E _{IN}	Input Noise Voltage (*)	$R_g = 0$		1.2	5	μV
SVR	Supply Voltage Rejection	$R_g = 0$; $f = 100Hz$; $V_r = 0.5V_{rms}$	45	50		dB
ASB	Stand-by Attenuation		60	90		dB
I _{SB}	ST-BY Current Consumption				100	μΑ
V _{SB IN}	ST-BY IN Threshold Voltage				1.5	V
V _{SB} OUT	ST-BY OUT Threshold Voltage		3.5			V
V _{M IN}	MUTE IN Threshold Voltage				1.5	V
V _{M OUT}	MUTE OUT Threshold Voltage		3.5			V

POWER SWITCH CHARACTERISTICS

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
I _{Op}	Continuous Output Current			1.2		Α
V_{DROP}	Dropout Voltage	Io = 1A			1.4	V

(*) 22Hz to 22KHz (**) A weighted

TEST AND APPLICATION CIRCUIT

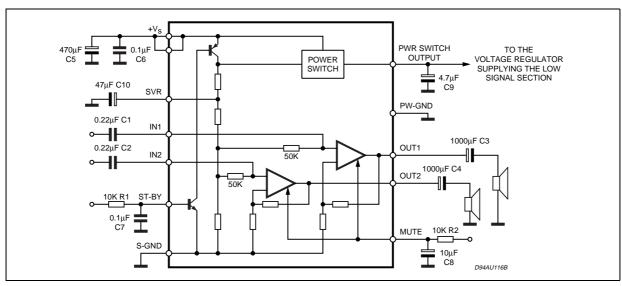


Figure 1: P.C.Board and component layout of the Test and Application Circuit 1:1 scale.

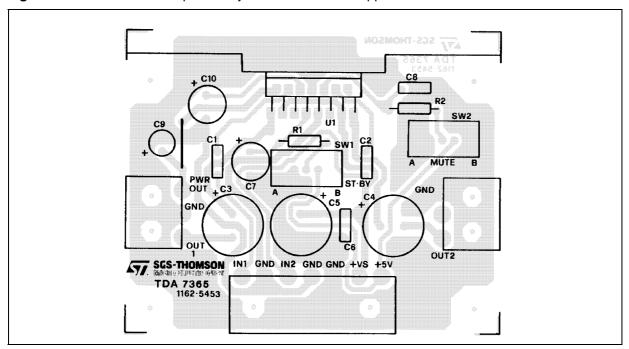


Figure 2: Quiescent Drain Current vs. Supply Voltage

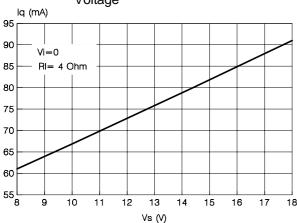


Figure 4: Output Power vs. Supply Voltage

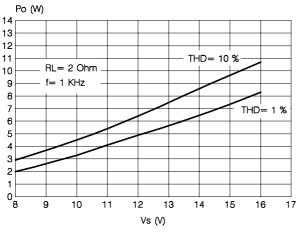


Figure 3: Output Power vs. Supply Voltage

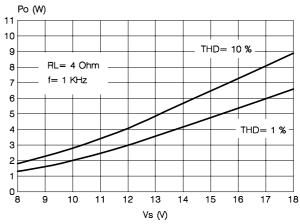
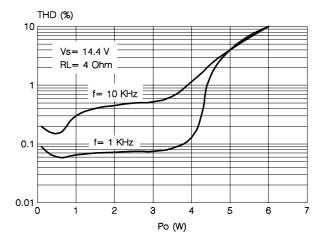


Figure 5: Distortion vs. Output Power



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Fiigure 6: Distortion vs. Frequency

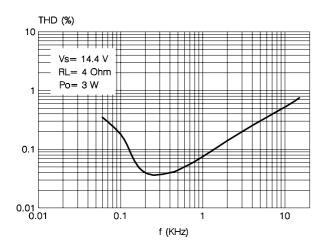
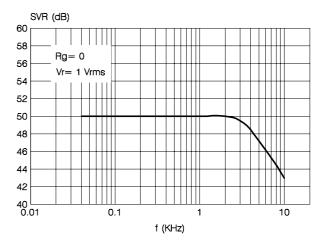


Figure 7: Supply Voltage Rejection



Fiigure 8: Cross-Talk vs. Frequency

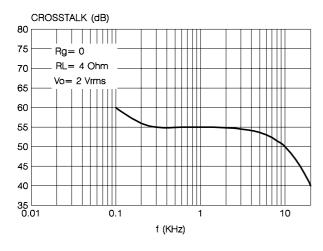


Figure 9: Switch Drop-out vs. Switch Current

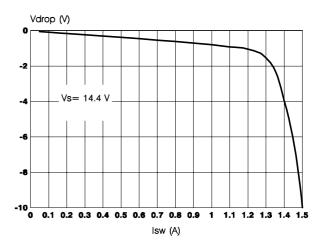


Figure 10: Total Power Dissipation and Efficiency vs. Output Power

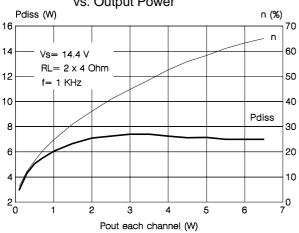
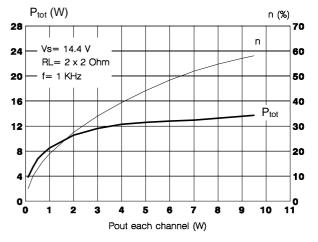
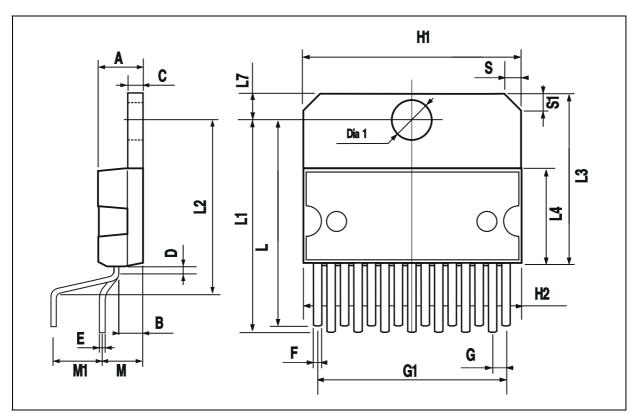


Figure 11: Total Power Dissipation and Efficiency



MULTIWATT15 PACKAGE MECHANICAL DATA

DIM.		mm		inch		
DIN.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α			5			0.197
В			2.65			0.104
С			1.6			0.063
D		1			0.039	
Е	0.49		0.55	0.019		0.022
F	0.66		0.75	0.026		0.030
G	1.14	1.27	1.4	0.045	0.050	0.055
G1	17.57	17.78	17.91	0.692	0.700	0.705
H1	19.6			0.772		
H2			20.2			0.795
L	22.1		22.6	0.870		0.890
L1	22		22.5	0.866		0.886
L2	17.65		18.1	0.695		0.713
L3	17.25	17.5	17.75	0.679	0.689	0.699
L4	10.3	10.7	10.9	0.406	0.421	0.429
L7	2.65		2.9	0.104		0.114
М	4.2	4.3	4.6	0.165	0.169	0.181
M1	4.5	5.08	5.3	0.177	0.200	0.209
S	1.9		2.6	0.075		0.102
S1	1.9		2.6	0.075		0.102
Dia1	3.65		3.85	0.144		0.152



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